

CAT809, CAT810

3-Pin Microprocessor Power Supply Supervisors



FEATURES

- Precision monitoring of
 - $+5.0 \text{ V } (\pm 5\%, \pm 10\%, \pm 20\%),$
 - $+3.3 \text{ V } (\pm 5\%, \pm 10\%),$
 - +3.0 V (± 10%) and
 - +2.5 V (\pm 5%) power supplies
- Offered in two output configurations:
 - CAT809: Active LOW reset
 - CAT810: Active HIGH reset
- Direct replacements for the MAX809 and MAX810 in applications operating over the industrial temperature range
- Reset valid down to V_{CC} = 1.0 V
- 6 µA power supply current
- Power supply transient immunity
- Available in SOT-23 and SC70 packages with Sn or NiPdAu GREEN lead finish
- Industrial temperature range: -40°C to +85°C

APPLICATIONS

- **■** Computers
- **■** Servers
- Laptops
- Cable modems
- Wireless communications
- **■** Embedded control systems
- White goods
- Power meters
- Intelligent instruments
- PDAs and handheld equipment

DESCRIPTION

The CAT809 and CAT810 are μP supervisory circuits that monitor power supplies in digital systems. The CAT809 and CAT810 are direct replacements for the MAX809 and MAX810 in applications operating over the industrial temperature range.

These devices generate a reset signal, which is asserted while the power supply voltage is below a preset threshold level and for at least 140 ms after the power supply level has risen above that level. The underlying floating gate technology, AE^{2(TM)} used by Catalyst Semiconductor, makes it possible to offer any custom reset threshold value. Seven industry standard threshold levels are offered to support +5.0 V, +3.3 V, +3.0 V and +2.5 V systems.

The CAT809 features a RESET push-pull output (active LOW) and the CAT810 features a RESET push-pull output (active HIGH).

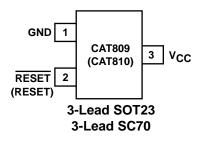
Fast transients on the power supply are ignored and the output is guaranteed to be in the correct state at V_{cc} levels as low as 1.0 V.

The CAT809/810 are fully specified over the industrial temperature range (-40°C to 85°C) and are available in compact 3-pin SOT23 and SC70 packages.

THRESHOLD SUFFIX SELECTOR

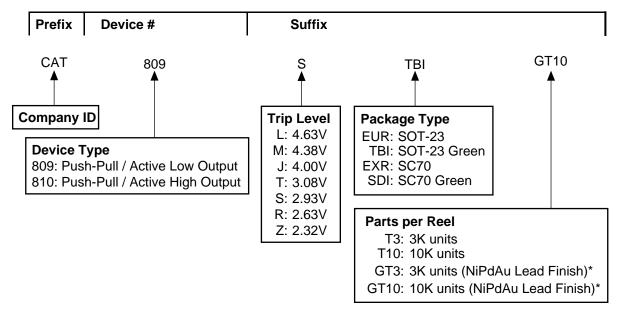
Nominal Threshold	Threshold Suffix
Voltage	Designation
4.63V	L
4.38V	М
4.00V	J
3.08V	Т
2.93V	S
2.63V	R
2.32V	Z

PIN CONFIGURATION





ORDERING INFORMATION



The device shown in the examples (CAT809STBI-GT10) has an Active Low, Push-Pull output; a trip level of 2.85V to 3.00V and is provided in the Green SOT-23 package with a NiPdAu lead finish on tape and reel with 10,000 units.

TOP MARKING

Parts and Threshold	SOT23 ⁽¹⁾	SOT-23 Green Sn Matte Lead Finish ⁽¹⁾	SOT-23 Green NiPdAu Lead Finish (1) (2)	SC70 ⁽¹⁾	SC70 Green Sn Matte Lead Finish ⁽¹⁾	SC70 Green NiPdAu Lead Finsish (1) (2)
CAT809L	AAYM	DBYM		FA_	GA_	
CAT809M	ABYM	DCYM		FB_	GB_	
CAT809J	CWYM	CAYM		FG_	GG_	
CAT809T	ACYM	DFYM	NRYM	FE_	GE_	NR_
CAT809S	ADYM	DEYM		FD_	GD_	
CAT809R	AFYM	DDYM		FC_	GC_	
CAT809Z	CFYM	DGYM		FF_	GF_	
CAT810L	AGYM	CKYM		FH_	GH_	
CAT810M	AHYM	CLYM		FJ_	GJ_	
CAT810J	AIYM	CJYM		FP_	GP_	
CAT810T	AJYM	СРҮМ	NSYM	FM_	GM_	NS_
CAT810S	AKYM	CNYM		FL_	GL_	
CAT810R	ALYM	СМҮМ		FK_	GK_	
CAT810Z	CGYM	CRYM		FN_	GN_	

Notes

^{*} NiPdAu is a Lead Finish Option on the Green Packages only. Unless indicated with the "G", green packages are shipped with a Sn Matte Lead Finish.

¹⁾ The "YM" in the SOT-23 package marking indicates the Year and Month of production and the "_" in the SC70 package marking indicates the assembly location.

²⁾ All NiPdAu devices will be marked to indicate product type and package. Threshold and full part numbers will be provided on box and reel labels as well as all Shipping documents.



PIN DESCRIPTIONS

Pin Nu	ımber	Name	Description
CAT809	CAT810	Name	Description
1	1	GND	Ground
2	_	RESET	Active LOW reset. $\overline{\text{RESET}}$ is asserted if V_{CC} falls below the reset threshold and remains low for at least 140ms after V_{CC} rises above the reset threshold.
_	2	RESET	Active HIGH reset. RESET is asserted if V_{CC} falls below the reset threshold and remains high for at least 140ms after V_{CC} rises above the reset threshold.
3	3	Vcc	Power supply voltage that is monitored.



ABSOLUTE MAXIMUM RATINGS*

Any pin with respect to ground0.3 V	' to +6.0 V
Input Current, V _{CC}	20 mA
Output Current, RESET, RESET	20 mA
Rate of Rise, V _{CC}	100 V/μs
Continuous Power Dissipation	
Derate 2.2mW/°C above 70°C (SC70)	175 mW
Derate 4mW/°C above 70°C (SOT23)	320 mW

Operating Temperature Range40°C to +85°C
Storage Temperature Range65°C to +105°C
Lead Soldering Temperature (10 sec) 300°C

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.

ELECTRICAL CHARACTERISTICS

 V_{CC} = Full range, T_A = -40°C to +85°C unless otherwise noted. Typical values at T_A = +25°C and V_{CC} = 5 V for the L/M/J versions, V_{CC} = 3.3 V for the T/S versions, V_{CC} = 3 V for the R version and V_{CC} = 2.5 V for the Z version.

*COMMENT

Parameter	Symbol	Condi	Min	Тур	Max	Units	
VCC Range		$T_A = 0$ °C to +70°C		1.0		5.5	V
		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		1.2		5.5	V
Supply Current	loo	T 40°C to 105°C	V _{CC} < 5.5 V, J/L/M		8	20	^
Supply Current	Icc	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	V _{CC} < 3.6 V, R/S/T/Z		6	15	μΑ
		I. Throohold	T _A = +25°C	4.56	4.63	4.70	
		L Threshold	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	4.50		4.75	
		M Threshold	T _A = +25°C	4.31	4.38	4.45	
			$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	4.25		4.50	
		J Threshold	T _A = +25°C	3.93	4.00	4.06	
5 .			$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	3.89		4.10	
Reset Threshold VTH		T Threehold	T _A = +25°C	3.04	3.08	3.11	
	T Threshold	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	3.00		3.15	V	
Voltage	VIII		T _A = +25°C	2.89	2.93	2.96	
		S Threshold	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	2.85		3.00	-
		5.71	T _A = +25°C	2.59	2.63	2.66	
		R Threshold	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.55		2.70	
		7 Threehold	T _A = +25°C	2.28	2.32	2.35	
		Z Threshold	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	2.25		2.38	



ELECTRICAL CHARACTERISTICS (continued)

 V_{CC} = Full range, T_A = -40°C to +85°C unless otherwise noted. Typical values at T_A = +25°C and V_{CC} = 5 V for L/M/J versions, V_{CC} = 3.3 V for T/S versions, V_{CC} = 3 V for R version and V_{CC} = 2.5 V for Z version.

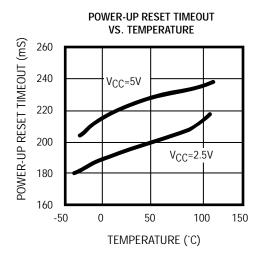
Parameter	Symbol	Conditions	Min	Typ ⁽¹⁾	Max	Units
Reset Threshold Tempco				30		ppm/°C
V _{CC} to Reset Delay (Note 2)		V _{CC} = V _{TH} to (V _{TH} - 100 mV)		20		μs
Reset Active Timeout Period		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	140	240	400	ms
RESET Output Voltage Low		$V_{CC} = V_{TH}$ min, $I_{SINK} = 1.2$ mA CAT809R/S/T/Z			0.3	
(Push-pull, active LOW, CAT809)	Vol	$V_{CC} = V_{TH} \text{ min, } I_{SINK} = 3.2 \text{ mA}$ $CAT809J/L/M$			0.4	V
		$V_{CC} > 1.0 \text{ V}, \text{ Isink} = 50 \mu\text{A}$			0.3	
RESET Output Voltage High	gh V _{OH}	$V_{CC} = V_{TH}$ max, $I_{SOURCE} = 500$ μA CAT809R/S/T/Z	0.8 V _{CC}			V
(Push-pull, active LOW, CAT809)	VOH	V _{CC} = V _{TH} max, I _{SOURCE} = 800 μA CAT809J/L/M	V _{CC} - 1.5			v
RESET Output Voltage Low (Push-pull, active HIGH,	VoL	$V_{CC} > V_{TH}$ max, $I_{SINK} = 1.2$ mA CAT810R/S/T/Z			0.3	V
CAT810)	VOL	$V_{CC} > V_{TH}$ max, $I_{SINK} = 3.2$ mA CAT810J/L/M			0.4	v
RESET Output Voltage High (Push-pull active HIGH, CAT810)	Vон	1.8 V < V _{CC} \leq V _{TH} min, I _{SOURCE} = 150 μ A	0.8 V _{CC}			V

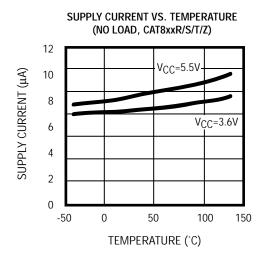
Note 1: Production testing done at $T_A = +25^{\circ}C$; limits over temperature guaranteed by design only. Note 2: \overline{RESET} output for the CAT809; RESET output for the CAT810

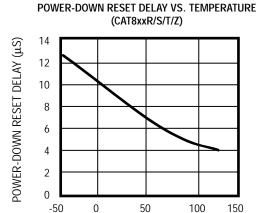


TYPICAL OPERATING CHARACTERISTICS

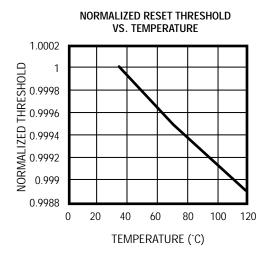
 V_{CC} = Full range, T_A = -40°C to +85°C unless otherwise noted. Typical values at T_A = +25°C and V_{CC} = 5 V for L/M/J versions, V_{CC} =3.3 V for T/S versions, V_{CC} = 3 V for R version and V_{CC} = 2.5 V for Z version.







TEMPERATURE (°C)





DETAILED DESCRIPTIONS

RESET TIMING

The reset signal is asserted LOW for the CAT809 and HIGH for the CAT810 when the power supply voltage falls below the threshold trip voltage and remains asserted for at least 140ms after the power supply voltage has risen above the threshold.

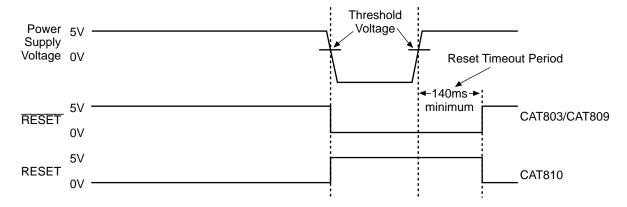


Figure 1. Reset Timing Diagram

VCC TRANSIENT RESPONSE

The CAT809/810 protect μPs against brownout failure. Short duration transients of $4\mu sec$ or less and 100 mV amplitude typically do not cause a false RESET.

Figure 2 shows the maximum pulse duration of negativegoing V_{CC} transients that do not cause a reset condition. As the amplitude of the transient goes further below the threshold (increasing V_{TH} - V_{CC}), the maximum pulse duration decreases. In this test, the V_{CC} starts from an initial voltage of 0.5V above the threshold and drops below it by the amplitude of the overdrive voltage (V_{TH} - V_{CC}).

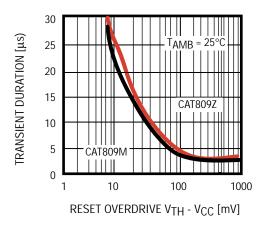


Figure 2. Maximum Transient Duration Without Causing a Reset Pulse vs. Reset Comparator Overdrive



VALID RESET WITH V_{CC} UNDER 1.0 V

To ensure that the CAT809 $\overline{\text{RESET}}$ pin is in a known state when V_{CC} is under 1.0 V, a 100 k Ω pull-down resistor between $\overline{\text{RESET}}$ pin and GND is recommended; the value is not critical. For the CAT810, a pull-up resistor from RESET pin to V_{CC} is needed.

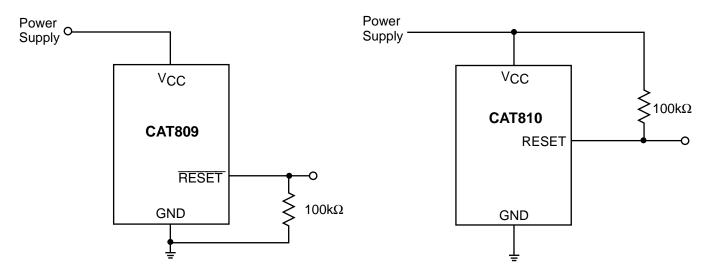


Figure 3. RESET Valid with V_{CC} Under 1.0 V

Figure 4. RESET Valid with V_{CC} Under 1.1 V

BI-DIRECTIONAL RESET PIN INTERFACING

The CAT809/810 can interface with $\mu P/\mu C$ bi-directional reset pins by connecting a 4.7 k Ω resistor in series with the CAT809/810 reset output and the $\mu P/\mu C$ bi-directional reset pin.

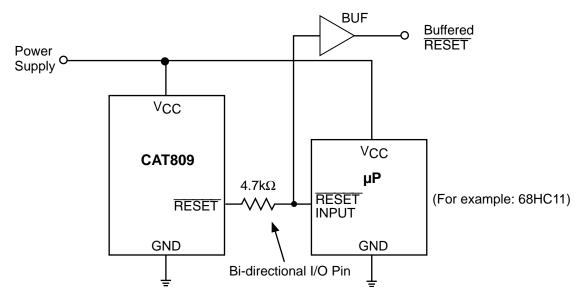


Figure 5. Bi-directional Reset Pin Interfacing

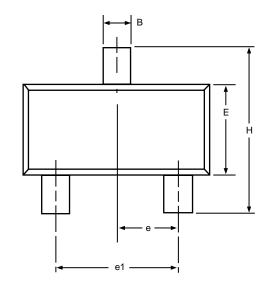


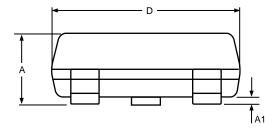
OTHER SUPERVISORY PRODUCTS

Function	CAT1161/3	CAT1162	CAT809	CAT810	CAT811	CAT812
With 16k Bit Serial EEPROM Memory	•	•				
Watchdog Timer	•					
Manual Reset Input	•	•			•	•
Active Low Reset			•		•	
Active High Reset				•		•
Dual Polarity Reset Outputs	•	•				
Package	8-pin DIP and SOIC	8-pin DIP and SOIC	3-pin SOT23 and SC70	3-pin SOT23 and SC70	4-pin SOT143	4-pin SOT143



PACKAGE INFORMATION Plastic SOT-23 (3-Pin)

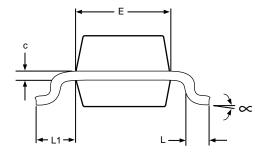




	Inch	ies	Millim	eters				
	Min	Max	Min	Max				
	Plastic SOT-23 (3-Pin)							
Α	0.0350	0.0441	0.89	1.12				
A1	0.0005	0.0039	0.013	0.10				
В	0.0146	0.0197	0.37	0.50				
С	0.0033	0.0071	0.085	0.18				
D	0.1102	0.1197	2.80	3.04				
Е	0.0472	0.0551	1.20	1.40				
е	0.0350	0.0406	0.89	1.03				
e1	0.0701	0.0807	1.78	2.05				
Н	0.0827	0.1039	2.10	2.64				
∞	0°	8°	0°	8°				
L	0.0083	0.0161	0.275	0.41				
L1	0.0160	0.0270	0.275	0.685				

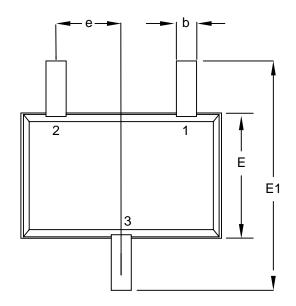
NOTE:

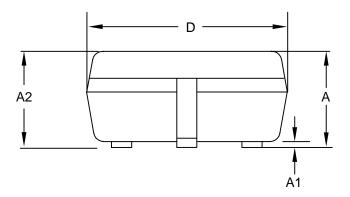
- 1. THIS PART IS COMPLIANT WITH JEDEC SPECIFICATION TO-236AB
- 2. DIE IS FACE UP FOR MOLD AND TRIM/FORM
- 3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR





PACKAGE INFORMATION SC-70 Package (3-Lead)

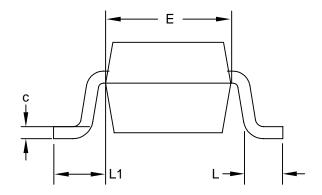




	Inch	nes	Millim	eters
	Min	Max	Min	Max
	Pla	astic SC-70 (3-Pin)	
Α	0.0315	0.0433	0.80	1.10
A1	0.0000	0.0039	0.00	0.10
A2	0.0315	0.0394	0.80	1.00
b	0.0059	0.00118	0.15	0.30
С	0.0035	0.0071	0.09	0.18
D	0.0709	0.0866	1.80	2.20
Е	0.0453	0.0531	1.15	1.35
E1	0.0709	0.0945	1.80	2.40
е	0.0025	5 BSC	0.65	BSC
L	0.0102	0.0181	0.26	0.46
L1	0.0108	0.0226	0.275	0.575

NOTE:

- 1. THIS PART IS COMPLIANT WITH EIAJ SPECIFICATION SC-70
- 2. DIE IS FACE UP FOR MOLD. DIE IS FACING DOWN FOR TRIM/FORM
- 3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR





REVISION HISTORY

Date	Rev.	Reason
10/29/2003	N	Updated VCC Transient Response text and Figure 2
10/30/2003	0	Updated Power Up Reset Timeout vs. Temperature curve
3/10/2004	Р	Corrected temperature range
		Updated Description
		Updated Ordering Information
		Updated Absolute Maximum Ratings
		Updated Electrical Characteristics
03/23/2004	Q	Updated Description
		Updated Ordering Information
		Updated Absolute Maximum Ratings
		Updated Electrical Characteristics
		Updated Typical Operating Characteristics
		Updated Package Information
3/25/2004	R	Changed Preliminary designation to Final
		Updated Max Reset Active Timout Period in Electrical Characteristics
		Updated package drawings
5/10/2004	S	Updated top marking table
12/28/2005	Т	Updated Features
		Updated Ordering Information
		Updated Top Marking

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Publication #: 3004 Revison: T

Issue date: 12/28/05